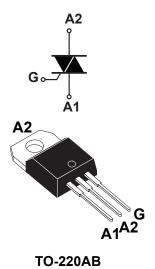


8 A - 800 V - 150 °C 8H Triac in TO-220AB



Features

- · 8 A medium current Triac
- · 800 V symmetrical blocking voltage
- 150 °C maximum junction temperature T_i
- · Three triggering quadrants
- High noise immunity static dV/dt
- Robust dynamic turn-off commutation (dl/dt)c
- ECOPACK2 compliant component
- Molding resin UL94-V0 flammability certified

Applications

- · Home automation smart AC plug
- · Water heater, room heater and coffee machine
- · AC Induction and universal motor control
- · Inrush current limiter in AC DC rectifiers
- · Lighting and automation I/O control
- General purpose AC line load control

Description

Specifically designed to operate at 800 V and 150 °C, the T835H-8T Triac housed in TO-220AB provides an enhanced thermal management: this 8 A Triac is the right choice for a compact drive of AC loads and enables the heatsink size reduction.

Based on the ST Snubberless high temperature technology, it offers higher specified turn off commutation and noise immunity levels up to the T_i max.

The T835H-8T safely optimizes the control of the hardest universal motors, heaters and inductive loads for industrial control and home appliances.

Snubberless is a trademark of STMicroelectronics.

Product status link	
T835H-8T	

Product summary		
I _{T(RMS)}	8 A	
V _{DRM} /V _{RRM}	800 V	
V _{DSM} /V _{RSM}	900 V	
I _{GT}	35 mA	
T _j max.	150 °C	



1 Characteristics

Table 1. Absolute maximum ratings (limiting values)

Symbol	Parameter	Value	Unit	
I _{T(RMS)}	RMS on-state current (full sine wave)	T _c = 139 °C	8	Α
I	Non repetitive surge peak on-state current	t = 16.7 ms	84	Δ.
I _{TSM}	(full cycle,T _j initial = 25 °C)	t = 20 ms	80	Α
I ² t	I ² t value for fusing	t _p = 10 ms	42	A ² s
dl/dt	Critical rate of rise of on-state current, $I_G = 2 \times I_{GT}, \text{ tr} \leq 100 \text{ ns}, \text{ f} = 100 \text{ Hz}$ $T_j = 25 \text{ °C}$		100	A/µs
V _{DRM} /V _{RRM}	Repetitive peak off-state voltage	800	V	
V _{DSM} /V _{RSM}	Non Repetitive peak off-state voltage $t_p = 10 \text{ ms}, T_j = 25 \text{ °C}$		900	V
I _{GM}	Peak gate current		4	Α
P _{GM}	Maximum gate power dissipation	t _p = 20 μs, T _j = 150 °C	5	W
P _{G(AV)}	Average gate power dissipation $T_j = 150 ^{\circ}\text{C}$		1	W
T _{stg}	Storage temperature range	-40 to +150	°C	
Tj	Operating junction temperature range -40 to +150 °C			
TL	Maximum lead temperature for soldering during	260	°C	

Table 2. Electrical characteristics (T_j = 25 °C, unless otherwise specified)

Symbol	Test conditions		Quadrants; T _j		Value	Unit
I _{GT}	$V_D = 12 \text{ V}, R_L = 30 \Omega$		1 - 11 - 111	Min.	5	mA
'G1	VD = 12 V, I(L = 50 12		1-11-111	Max.	35	mA
V_{GT}	V_D = 12 V, R_L = 30 Ω		1 - 11 - 111	Max.	1.3	V
V_{GD}	$V_D = V_{DRM}$, $R_L = 3.3 \text{ k}\Omega$	T _j = 150 °C	1 - 11 - 111	Min.	0.15	V
I.	I _L		1 - 111	Max.	50	mA
'L			II	П	Max.	80
I _H ⁽¹⁾	I _T = 500 mA, gate open		Max.	35	mA	
dV/dt (1)	$V_D = V_R = 536 \text{ V}$, gate open		T _j = 150 °C	Min.	2000	V/µs
(dl/dt)c (1)	Without snubber network		T _j = 150 °C	Min.	8	A/ms

^{1.} For both polarities of A2 referenced to A1.

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Table 3. Static characteristics

Symbol	Test conditions	Tj		Value	Unit
V _{TM} ⁽¹⁾	I _{TM} = 11 A, t _p = 380 μs	25 °C	Max.	1.50	V
V _{TO} ⁽¹⁾	Threshold voltage	150 °C	Max.	0.83	V
R _D ⁽¹⁾	Dynamic resistance	150 °C	Max.	45	mΩ
	$V_D = V_R = V_{DRM} = V_{RRM}$	25 °C	Max.	1.5	μA
I _{DRM} /I _{RRM}	VD - VR - VDRM - VRRM	150°C	IVIAX.	3.5	mA
	V _D = V _R = 400 V, peak voltage	150 °C	Max.	1.3	mA

^{1.} For both polarities of A2 referenced to A1.

Table 4. Thermal resistance

Symbol	Parameter	Value	Unit	
R _{th(j-c)}	Junction to case (AC)	Max.	1.2	°C/W
R _{th(j-a)}	Junction to ambient	Тур.	60	°C/W



0

0.5

0

25

50

1.1 Characteristics (curves)

Figure 1. Maximum power dissipation versus on-state RMS current (full cycle)

P(W)

a = 180°

 $I_{T(RMS)}(A)$

Figure 3. On-state RMS current versus ambient temperature (free air convection)

IT(RMS)(A)

a = 180°

Ta(°C)

75

100

125

150

Figure 4. On-state characteristics (maximum values) $\begin{matrix} I_{TM}(A) \\ I_{0} \\ I$

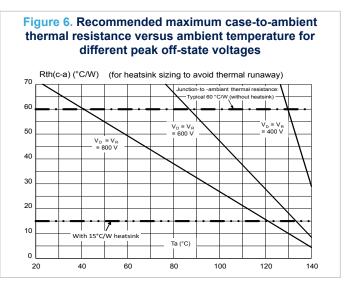
Figure 5. Relative variation of thermal impedance versus pulse duration

K = [Zth/Rth]

1.0E-01

1.0E-02

1.0E-03



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Figure 7. Relative variation of gate trigger voltage and current versus junction temperature (typical values)

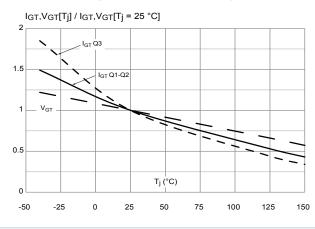


Figure 8. Relative variation of holding current and latching current versus junction temperature (typical values)

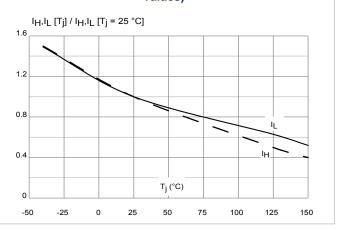


Figure 9. Surge peak on-state current versus number of cycles

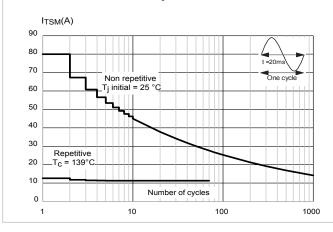


Figure 10. Non repetitive surge peak on-state current for a sinusoidal pulse with width $t_{\rm p}$ < 10 ms

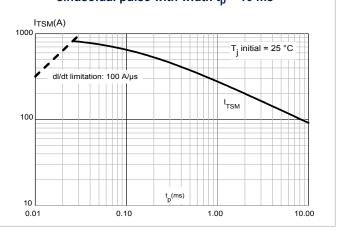


Figure 11. Relative variation of static dV/dt immunity versus junction temperature

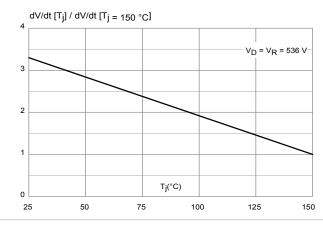
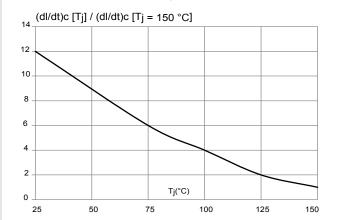
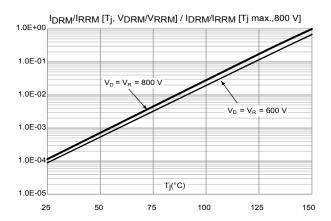


Figure 12. Relative variation of critical rate of decrease of main current versus junction temperature



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Figure 13. Relative variation of leakage current versus junction temperature for different values of blocking voltage



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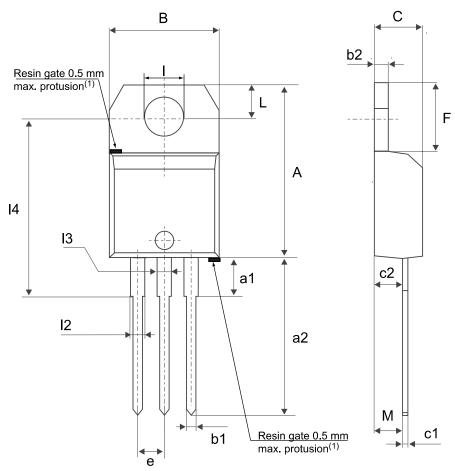
Package information

In order to meet environmental requirements, ST offers these devices in different grades of ECOPACK packages, depending on their level of environmental compliance. ECOPACK specifications, grade definitions and product status are available at: www.st.com. ECOPACK is an ST trademark.

2.1 TO-220AB package information

- Epoxy resin is halogen free and meets UL94 flammability standard, level V0
- Lead-free plating package leads
- Recommended torque: 0.4 to 0.6 N·m

Figure 14. TO-220AB package outline



(1)Resin gate position accepted in one of the two positions or in the symmetrical opposites.

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Table 5. TO-220AB package mechanical data

			Di	mensions		
Ref.		Millimeters			Inches ⁽¹⁾	
	Min.	Тур.	Max.	Min.	Тур.	Max.
Α	15.20		15.90	0.5984		0.6260
a1		3.75			0.1476	
a2	13.00		14.00	0.5118		0.5512
В	10.00		10.40	0.3937		0.4094
b1	0.61		0.88	0.0240		0.0346
b2	1.23		1.32	0.0484		0.0520
С	4.40		4.60	0.1732		0.1811
c1	0.49		0.70	0.0193		0.0276
c2	2.40		2.72	0.0945		0.1071
е	2.40		2.70	0.0945		0.1063
F	6.20		6.60	0.2441		0.2598
I	3.73		3.88	0.1469		0.1528
L	2.65		2.95	0.1043		0.1161
12	1.14		1.70	0.0449		0.0669
13	1.14		1.70	0.0449		0.0669
14	15.80	16.40	16.80	0.6220	0.6457	0.6614
М		2.6			0.1024	

^{1.} Inch dimensions are for reference only.

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3 Ordering information

Figure 15. Ordering information scheme

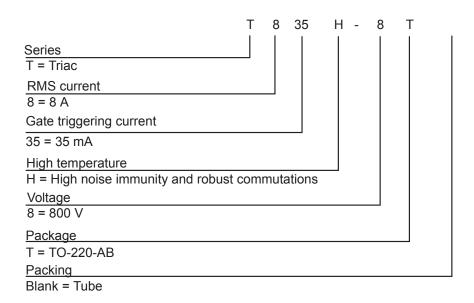


Table 6. Ordering information

Order code	Marking	Package	Weight	Base qty.	Delivery mode
T835H-8T	T835H-8T	TO-220AB	2.1 g	50	Tube

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Revision history

Table 7. Document revision history

Date	Version	Changes
20-Nov-2020	1	Initial release.
11-Dec-2020	2	Updated general description. Updated Table 6.



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